



CHENMKO ENTERPRISE CO.,LTD

Halogens free devices

SURFACE MOUNT

FAST SWITCHING DIODE ARRAY
VOLTAGE 75 Volts CURRENT 215 mAmpere

BAV99DGP

APPLICATION

- * Ultra high speed switching
- * For general purpose switching application

FEATURE

- * Small surface mounting type. (SC-88/SOT-363)
- * High speed. (TRR=1.5nSec Typ.)
- * Suitable for high packing density.
- * Maximum total power dissipation is 300mW.
- * Peak forward current is 350mA.

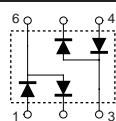
CONSTRUCTION

- * Silicon epitaxial planar

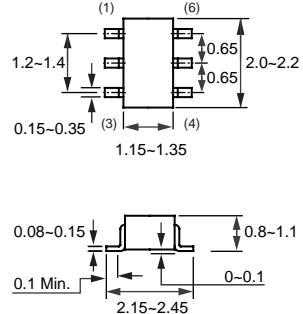
MARKING

- * 7D

CIRCUIT



SC-88/SOT-363



Dimensions in millimeters

SC-88/SOT-363

MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	BAV99DGP	UNITS
Maximum Non-Repetitive Peak Reverse Voltage	V _{RM}	100	Volts
Maximum RMS Voltage	V _{RMS}	53	Volts
Maximum Repetitive Peak Reverse and DC Blocking Voltage	V _{RRM} , V _{DC}	75	Volts
Maximum Average Forward Rectified Current	I _o	215	mAmps
Non-Repetitive Peak Forward Surge Current @t=1.0uSec @t=1.0Sec	I _{FSM}	2.0 1.0	Amps
Typical Junction Capacitance between Terminal (Note 1)	C _J	2.0	pF
Maximum Reverse Recovery Time (Note 2)	T _{RR}	4.0	nSec
Thermal Resistance Junction to Ambient (Note 3)	R _{θJA}	625	°C/W
Maximum Operating and Storage Temperature Range	T _o , T _{STG}	-65 to +150	°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	BAV99DGP	UNITS
Maximum Instantaneous Forward Voltage @I _f =1.0mA @I _f =10mA @I _f =50mA @I _f =150mA	V _F	0.715 0.855 1.00 1.25	Volts
Maximum Average Reverse Current @V _R =20V @V _R =75V @V _R =25V, T _J =150°C @V _R =75V, T _J =150°C	I _R	25 2.5 30 50	nAmps uAmps uAmps uAmps

- NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 0 volts.
 2. Measured at applied forward current of 10mA and reverse current of 10mA.
 3. Device mounted on FR-4 by 1 inch X 0.85 inch X 0.062 inch
 4. ESD sensitive product handling required.

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RATING CHARACTERISTIC CURVES (BAV99DGP)

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

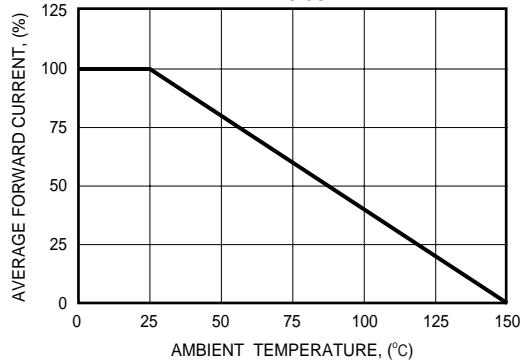


FIG. 2 - FORWARD CHARACTERISTICS

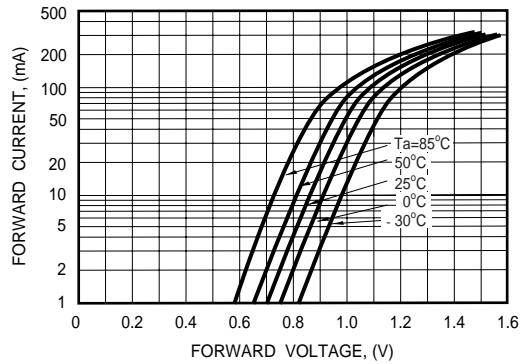


FIG. 3 - TYPICAL JUNCTION CAPACITANCE

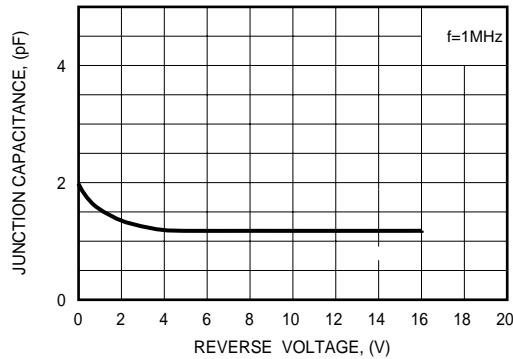


FIG. 4 - REVERSE CHARACTERISTICS

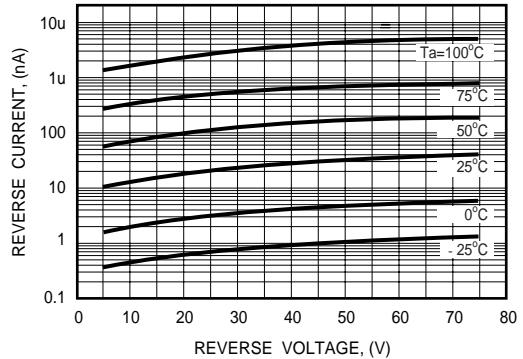


FIG. 5 - REVERSE RECOVERY TIME

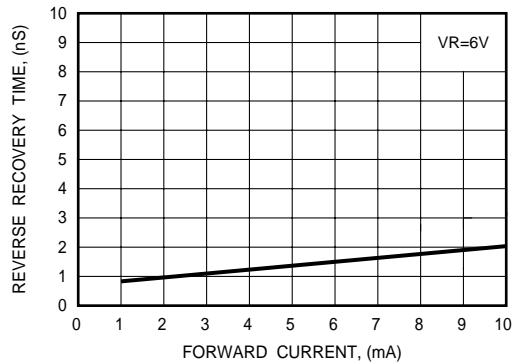


FIG. 6 - REVERSE RECOVERY TIME MEASUREMENT CIRCUIT

